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- Wide Bandwidth . . . 10 MHz
- High Output Drive

 I_{OH}... 57 mA at V_{DD} 1.5
 I_{OL}... 55 mA at 0.5 V
- High Slew Rate
 SR+...16 V/μs
- SR–...19 V/μs
- Wide Supply Range . . . 4.5 V to 16 V
- Supply Current . . . 1.9 mA/Channel
- Ultra-Low Power Shutdown Mode I_{DD}...125 μA/Channel
- Low Input Noise Voltage ... 7 nV√Hz
- Input Offset Voltage ... 60 μV
- Ultra-Small Packages
 8 or 10 Pin MSOP (TLC070/1/2/3)

description

TI C070 D, DGN OR P PACKAGE (TOP VIEW) 10 NULL I 8 II V_{DD} $IN - \Box$ 2 7 IN+ 🗆 3-6 GND □ 5 D NULL 4

Introducing the first members of TI's new BiMOS general-purpose operational amplifier family—the TLC07x. The BiMOS family concept is simple: provide an upgrade path for BiFET users who are moving away from dual-supply to single-supply systems and demand higher ac and dc performance. With performance rated from 4.5 V to 16 V across commercial (0°C to 70°C) and an extended industrial temperature range (-40°C to 125°C), BiMOS suits a wide range of audio, automotive, industrial and instrumentation applications. Familiar features like offset nulling pins, and new features like MSOP PowerPAD[™] packages and shutdown modes, enable higher levels of performance in a multitude of applications.

Developed in TI's patented LBC3 BiCMOS process, the new BiMOS amplifiers combine a very high input impedance low-noise CMOS front end with a high-drive Bipolar output stage—thus providing the optimum performance features of both. AC performance improvements over the TL07x BiFET predecessors include a bandwidth of 10 MHz (an increase of 300%) and voltage noise of 7 nV/ $\sqrt{\text{Hz}}$ (an improvement of 60%). DC improvements include a factor of 4 reduction in input offset voltage down to 1.5 mV (maximum) in the standard grade, and a power supply rejection improvement of greater than 40 dB to 130 dB. Added to this list of impressive features is the ability to drive \pm 50-mA loads comfortably from an ultra-small-footprint MSOP PowerPAD package, which positions the TLC07x as the ideal high-performance general-purpose operational amplifier family.

FAMILY PACKAGE TABLE

DEVICE	NO. OF		PACKAG	E TYPES	-	SHUTDOWN	UNIVERSAL
DEVICE	CHANNELS	MSOP	PDIP	SOIC	TSSOP	SHOTDOWN	EVM BOARD
TLC070	1	8	8	8	—	Yes	
TLC071	1	8	8	8	—		
TLC072	2	8	8	8	—	—	Refer to the EVM
TLC073	2	10	14	14	—	Yes	Selection Guide (Lit# SLOU060)
TLC074	4	_	14	14	20	_	(
TLC075	4	_	16	16	20	Yes	



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TLC070 and TLC071 AVAILABLE OPTIONS

	PACKAGED DEVICES	PAC	CKAGED DEVICES			
T _A	SMALL OUTLINE (D) [†]	SMALL OUTLINE (DGN) [†]	SYMBOL	PLASTIC DIP (P)		
0°C to 70°C	TLC070CD TLC071CD	TLC070CDGN TLC071CDGN	xxTIACS xxTIACU	TLC070CP TLC071CP		
−40°C to 125°C	TLC070ID TLC071ID	TLC070IDGN TLC071IDGN	xxTIACT xxTIACV	TLC070IP TLC071IP		
40 0 10 120 0	TLC070AID TLC071AID			TLC070AIP TLC071AIP		

⁺ This package is available taped and reeled. To order this packaging option, add an R suffix to the part number (e.g., TLC070CDR). [‡] Chip forms are tested at $T_A = 25^{\circ}C$ only.

TLC072 and TLC073 AVAILABLE OPTIONS

		PACKAGED DEVICES								
TA	SMALL MSOP				PLASTIC	PLASTIC				
	OUTLINE (D)†	(DGN)†	SYMBOL§	(DGQ)†	SYMBOL§	DIP (N)	DIP (P)			
0°C to 70°C	TLC072CD TLC073CD	TLC072CDGN —	xxTIADV —	 TLC073CDGQ	 xxTIADX		TLC072CP —			
-40°C to 125°C	TLC072ID TLC073ID	TLC072IDGN —	xxTIADW —		 xxTIADY		TLC072IP —			
-40 0 10 123 0	TLC072AID TLC073AID						TLC072AIP —			

[†] This package is available taped and reeled. To order this packaging option, add an R suffix to the part number (e.g., TLC072CDR). [‡] Chip forms are tested at $T_A = 25^{\circ}C$ only.

 $\$ xx represents the device date code.

TLC074 and TLC075 AVAILABLE OPTIONS

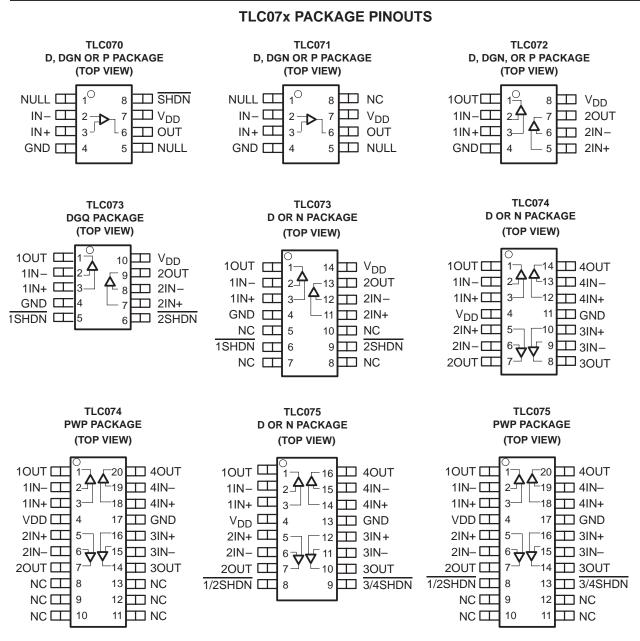
	PACKAGED DEVICES						
TA	SMALL OUTLINE	PLASTIC DIP	TSSOP				
	(D) [†]	(N)	(PWP) [†]				
0°C to 70°C	TLC074CD	TLC074CN	TLC074CPWP				
	TLC075CD	TLC075CN	TLC075CPWP				
−40°C to 125°C	TLC074ID	TLC074IN	TLC074IPWP				
	TLC075ID	TLC075IN	TLC075IPWP				
40 0 10 120 0	TLC074AID	TLC074AIN	TLC074AIPWP				
	TLC075AID	TLC075AIN	TLC075AIPWP				

[†]This package is available taped and reeled. To order this packaging option, add an R suffix to the part number (e.g., TLC074CDR).

 \ddagger Chip forms are tested at TA = 25°C only.



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NC - No internal connection



TLC070, TLC071, TLC072, TLC073, TLC074, TLC075, TLC07xA FAMILY OF WIDE-BANDWIDTH HIGH-OUTPUT-DRIVE SINGLE SUPPLY OPERATIONAL AMPLIFIERS SLOS219B – JUNE 1999 – REVISED NOVEMBER 1999

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)[†]

Supply voltage, V _{DD} (see Note 1) Differential input voltage, V _{ID}	
Continuous total power dissipation	
Operating free-air temperature range, T _A : C suffix	0°C to 70°C
I suffix	–40°C to 125°C
Maximum junction temperature, T _J	150°C
Storage temperature range, T _{stg}	–65°C to 150°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds	260°C

⁺ Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTE: All voltage values, except differential voltages, are with respect to GND.

	DISSIPATION F	RATING TABLE	
PACKAGE	θJC (°C/W)	^θ ЈА (°С/W)	T _A ≤ 25°C POWER RATING
D (8)	38.3	176	710 mW
D (14)	26.9	122.3	1022 mW
D (16)	25.7	114.7	1090 mW
DGN (8)	4.7	52.7	2.37 W
DGQ (10)	4.7	52.3	2.39 W
N (14, 16)	32	78	1600 mW
P (8)	41	104	1200 mW
PWP (20)	1.40	26.1	4.79 W

recommended operating conditions

		MIN	MAX	UNIT
	Single supply	4.5	16	V
Supply voltage, V _{DD}	Split supply	Single supply 4.5 16 Split supply ±2.25 ±8 +0.5 VDD-0.8 V C-suffix 0 70		
Common-mode input voltage range, VICR		+0.5	V _{DD} -0.8	V
Operating free air temperature T	C-suffix	0	70	°C
Common-mode input voltage range, VICR	-40	125	C	



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	PARAMETER	TEST CO	NDITIONS	T _A †	MIN	TYP	MAX	UNIT
				25°C		60	1000	
			TLC070/1/2/3	Full range			1500	μV
			TI 0070/1/0/0	25°C		20	750	
		V _{DD} = 5 V,	TLC070/1/2/3A	Full range			1000	
VIO	Input offset voltage	$V_{\rm IC} = 2.5,$		25°C		390	1900	
		V _O = 2.5,	TLC074/5	Full range			3000	
		R _S = 50 Ω		25°C		390	1400	
			TLC074/5A	Full range			2000	
αVIO	Temperature coefficient of input offset voltage					1.2		μV/°C
				25°C		0.7	50	
lio	Input offset current		TLC07XC				100	pА
		V _{DD} = 5 V, V _{IC} = 2.5,	TLC07XI	Full range			700	
		V _O = 2.5,		25°C		1.5	50	
I _{IB}	Input bias current	R _S = 50 Ω	TLC07XC				100	pА
			TLC07XI	Full range			700	
VICR Common-mod VICR range		CMRR > 70 dB,	R _S = 50 Ω	25°C	0.5 to 4.2			
	Common-mode input voltage range	CMRR > 52 dB,	R _S = 50 Ω	Full range	0.5 to 4.2			V
				25°C	4.1	4.3		
			$I_{OH} = -1 \text{ mA}$	Full range	3.9			
					25°C	3.7	4	
		V _{IC} = 2.5 V	$V_{IC} = 2.5 \text{ V}$ $I_{OH} = -35 \text{ mA}$	Full range	3.5			v
Vон	High-level output voltage			25°C	3.4	3.8		
				Full range	3.2			
				25°C	3.2	3.6		
			I _{OH} = -50 mA	-40°C to 85°C	3			
			1. 1	25°C		0.18	0.25	
			I _{OL} = 1 mA	Full range			0.35	1
				25°C		0.35	0.39	
			I _{OL} = 20 mA	Full range			0.45	1
VOL	Low-level output voltage	V _{IC} = 2.5 V	0.5	25°C		0.43	0.55	V
			I _{OL} = 35 mA	Full range			0.7	1
				25°C		0.48	0.63	
			I _{OL} = 50 mA	-40°C to 85°C			0.7	
		Sourcing		25°C		100		A
OS	Short-circuit output current	Sinking		25°C		100		mA
		$V_{OH} = 1.5 V$ from po	ositive rail	25°C		57		
0	Output current	$V_{OL} = 0.5 V$ from negative rail		25°C		55		mA

electrical characteristics at specified free-air temperature $V_{DD} = 5 V$ (unless otherwise noted)

[†] Full range is 0°C to 70°C for C suffix and -40°C to 125°C for I suffix. If not specified, full range is -40°C to 125°C.



TLC070, TLC071, TLC072, TLC073, TLC074, TLC075, TLC07xA FAMILY OF WIDE-BANDWIDTH HIGH-OUTPUT-DRIVE SINGLE SUPPLY OPERATIONAL AMPLIFIERS SLOS219B – JUNE 1999 – REVISED NOVEMBER 1999

electrical characteristics at specified free-air temperature, $V_{DD} = 5 V$ (unless otherwise noted) (continued)

	PARAMETER	TEST CON	DITIONS	т _А †	MIN	TYP	MAX	UNIT
A. (5)	Large-signal differential voltage		D 40.60	25°C	100	120		dB
AVD	amplification	V _{O(PP)} = 3 V,	R _L = 10 kΩ	Full range	100			uБ
^r i(d)	Differential input resistance			25°C		1000		GΩ
CIC	Common-mode input capacitance	f = 10 kHz		25°C		22.9		pF
z _o	Closed-loop output impedance	f = 10 kHz,	A _V = 10	25°C		0.25		Ω
CMRR	Common-mode rejection ratio	V _{IC} = 1 to 3 V,	R _S = 50 Ω	25°C	100	140		dB
				Full range	100			
kourp	Supply voltage rejection ratio	V _{DD} = 4.5 V to 16 V,	$V_{IC} = V_{DD}/2$,	25°C	95	130		dB
^k SVR	$(\Delta V_{DD} / \Delta V_{IO})$	No load	-	Full range	95			uВ
	Supply current	$V_{0} = 2.5 V_{1}$	No load	25°C		1.9	2.5	mA
DD	(per channel)	$v_0 = 2.5 v,$	No loau	Full range			3.5	mA
V _(ON)	Turnon voltage level	Relative to GND		25°C		1.41		V
V(OFF)	Turnoff voltage level	Relative to GND		25°C		1.4		V
IDD(SHDN)	Supply current in shutdown mode (per channel)	SHDN < 1.45 V		25°C		125	200	μA
	(TLC070, TLC073, TLC075)			Full range			250	port

[†] Full range is 0°C to 70°C for C suffix and –40°C to 125°C for I suffix. If not specified, full range is –40°C to 125°C.



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	PARAMETER	TEST CONDI	TIONS	T _A †	MIN	TYP	MAX	UNIT	
SR+	Positive slew rate at unity gain	V _{O(PP)} = 0.8 V,	CL = 50 pF,	25°C	10	16		V/µs	
OIT	r oshive siew rate at unity gain	R _L = 10 kΩ		Full range	9.5			ν/μ3	
SR-	Negative slew rate at unity gain	V _{O(PP)} = 0.8 V,	CL = 50 pF,	25°C	12.5	19		V/µs	
511-	Negative siew rate at unity gain	R _L = 10 kΩ		Full range	10			v/μs	
Vn	Equivalent input noise voltage	f = 100 Hz		25°C		12		nV/√Hz	
۷n	Equivalent input hoise voltage	f = 1 kHz		25°C		7			
In	Equivalent input noise current	f = 1 kHz		25°C		0.6		fA/√Hz	
		V _{O(PP)} = 3 V,	$A_V = 1$			0.002%			
THD + N	Total harmonic distortion plus noise	$R_L = 10 \ k\Omega$ and 250 Ω ,	A _V = 10	25°C		0.012%			
		f = 1 kHz	A _V = 100	7		0.085%			
t(on)	Amplifier turnon time‡	D 4040	25°C		0.15		μs		
^t (off)	Amplifier turnoff time‡	$R_{L} = 10 \text{ k}\Omega$		25°C	1.3			μs	
	Gain-bandwidth product	f = 10 kHz,	$R_L = 10 \ k\Omega$	25°C		10		MHz	
		V(STEP)PP = 1 V, A _V = -1,	0.1%			0.18			
ts	Settling time	C _L = 10 pF, R _L = 10 kΩ	0.01%	25°C		0.39		μs	
.2		V(STEP)PP = 1 V, $A_V = -1,$	0.1%	20 0		0.18		μο	
		$C_L = 47 \text{ pF},$ $R_L = 10 \text{ k}\Omega$	0.01%			0.39			
<i>ф</i>	Phase margin	R _L = 10 kΩ,	$C_L = 50 \text{ pF}$	25°C		32°			
фт	Phase margin	R _L = 10 kΩ,	C _L = 0 pF	200		40°			
		R _L = 10 kΩ,	C _L = 50 pF	0500		2.2		JD	
	Gain margin	$R_{I} = 10 \text{ k}\Omega,$	C _I = 0 pF	25°C		3.3		dB	

... • • -

[†] Full range is 0°C to 70°C for C suffix and -40°C to 125°C for I suffix. If not specified, full range is -40°C to 125°C.

[‡] Disable time and enable time are defined as the interval between application of the logic signal to SHDN and the point at which the supply current has reached half its final value.



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electrical characteristics at specified free-air temperature, V_{DD} = 12 V (unless otherwise noted)

	PARAMETER	TEST CO	NDITIONS	T _A †	MIN	TYP	MAX	UNIT					
			TI 0070/4/0/0	25°C		60	1000						
			TLC070/1/2/3	Full range			1500						
			TI 0070/4/0/0A	25°C		20	750						
.,		V _{DD} = 12 V	TLC070/1/2/3A	Full range			1000						
VIO	Input offset voltage	V _{IC} = 6,		25°C		390	1900	μV					
		VO = 6,		Full range			3000						
		R _S = 50 Ω	TI 0074/54	25°C		390	1400						
			TLC074/5A	Full range			2000						
αNIO	Temperature coefficient of input offset voltage]				1.2		μV/°C					
				25°C		0.7	50						
IIO	Input offset current	V _{DD} = 12 V	TLC07xC				100	pА					
		$V_{IC} = 6,$	TLC07xI	Full range			700						
		V _O = 6,		25°C		1.5	50						
I _{IB}	Input bias current	R _S = 50 Ω	TLC07xC				100	pА					
			TLC07xI	Full range			700						
Common-mode input voltage		CMRR > 70 dB	R _S = 50 Ω	25°C	0.5 to 11.2								
VICR	/ICR range	CMRR > 52 dB	R _S = 50 Ω	Full range	0.5 to			V					
					11.2								
			I _{OH} = -1 mA	25°C	11.1	11.2							
				Full range	11								
								I _{OH} = -20 mA	25°C	10.8	10.9		
					Full range	10.7							
Vон	High-level output voltage	VIC = 6 V	I _{OH} = -35 mA	25°C	10.6	10.7		V					
				Full range	10.3								
				25°C	10.4	10.5							
			I _{OH} = -50 mA	-40°C to 85°C	10.3								
			I _{OL} = 1 mA	25°C		0.17	0.25						
			.OL	Full range			0.35						
			I _{OL} = 20 mA	25°C		0.35	0.45						
			OL	Full range			0.5						
Vol	Low-level output voltage	V _{IC} = 6 V	I _{OL} = 35 mA	25°C		0.4	0.52	V					
			.OL	Full range			0.6						
			25°C		0.45	0.6							
		I _{OL} = 50 mA	–40°C to 85°C			0.65							
00	Short-circuit output current	Sourcing		25°C		150		mA					
OS		Sinking		25°C		150		AIII					
		$V_{OH} = 1.5 V$ from p	ositive rail	25°C		57		-					
0	Output current	$V_{OL} = 0.5 V$ from ne	egative rail	25°C		55		mA					

[†] Full range is 0°C to 70°C for C suffix and -40°C to 125°C for I suffix. If not specified, full range is -40°C to 125°C.



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electrical characteristics at specified free-air temperature, $V_{DD} = 12$ V (unless otherwise noted) (continued)

	PARAMETER	TEST CON	DITIONS	т _А †	MIN	TYP	MAX	UNIT
A	Large-signal differential voltage		D 4010	25°C	120	140		dB
AVD	amplification	VO(PP) = 8 V,	$R_L = 10 k\Omega$	Full range	120			uБ
^r i(d)	Differential input resistance			25°C		1000		GΩ
C _{IC}	Common-mode input capacitance	f = 10 kHz		25°C		21.6		pF
z ₀	Closed-loop output impedance	f = 10 kHz,	A _V = 10	25°C		0.25		Ω
CMRR (Common-mode rejection ratio	$V_{IC} = 1$ to 10 V, $R_S = 50$	Da 50.0	25°C	100	140		dB
			NS = 50 22	Full range	100			üD
kourp	Supply voltage rejection ratio	V _{DD} = 4.5 V to 16 V,	$V_{IC} = V_{DD}/2$,	25°C	95	130		dB
k SVR	$(\Delta V_{DD} / \Delta V_{IO})$	No load	-	Full range	95			uВ
	Supply current	$V_{0} = 7.5 V_{1}$	No load	25°C		2.1	2.9	mA
DD	(per channel)	$V_{0} = 7.5 V,$	NO IDAU	Full range			3.5	III/A
V _(ON)	Turnon voltage level	Relative to GND		25°C		1.39		V
V(OFF)	Turnoff voltage level	Relative to GND		25°C		1.38		V
IDD(SHDN)	Supply current in shutdown mode (TLC070, TLC073,	<u>SHDN</u> ≤ 1.45 V		25°C		125	200	μA
(אוטחפ)טטי	TLC075) (per channel)			Full range			250	μπ

[†] Full range is 0°C to 70°C for C suffix and -40°C to 125°C for I suffix. If not specified, full range is -40°C to 125°C.



TLC070, TLC071, TLC072, TLC073, TLC074, TLC075, TLC07xA FAMILY OF WIDE-BANDWIDTH HIGH-OUTPUT-DRIVE SINGLE SUPPLY OPERATIONAL AMPLIFIERS SLOS219B – JUNE 1999 – REVISED NOVEMBER 1999

operating characteristics at specified free-air temperature, V_{DD} = 12 V (unless otherwise noted)

	PARAMETER	TEST CONDI	TIONS	T _A †	MIN	TYP	MAX	UNIT
SR+	Positive slew rate at unity gain	V _{O(PP)} = 2 V,	C _L = 50 pF,	25°C	10	16		V/μs
		R _L = 10 kΩ		Full range	9.5			v/μS
SR-	Negative slew rate at unity gain	V _{O(PP)} = 2 V, R _L = 10 kΩ	C _L = 50 pF,	25°C	12.5	19		V/µs
				Full range	10			
V _n	Equivalent input noise voltage	f = 100 Hz		25°C		12		nV/√Hz
		f = 1 kHz		25°C		7		
I _n	Equivalent input noise current	f = 1 kHz	_	25°C		0.6		fA/√Hz
THD + N	Total harmonic distortion plus noise	$V_{O(PP)} = 8 V.$	$A_V = 1$			0.002%		
		$V_{O}(PP) = 8 \text{ V},$ R _L = 10 k Ω and 250 Ω , f = 1 kHz	A _V = 10	25°C		0.005%		
			A _V = 100			0.022%		
^t (on)	Amplifier turnon time‡	R _I = 10 kΩ		25°C		0.47		μs
^t (off)	Amplifier turnoff time‡			25°C		2.5		μs
	Gain-bandwidth product	f = 10 kHz,	$R_L = 10 \ k\Omega$	25°C		10		MHz
t _s	Settling time	$V_{(STEP)PP} = 1 V,$ Ay = -1, C _L = 10 pF, R _L = 10 kΩ	0.1%	– 25°C		0.17		· μs
			0.01%			0.22		
		$V(STEP)PP = 1 V, Ay = -1, CL = 47 pF, RL = 10 k\Omega$	0.1%	20 0		0.17		
			0.01%			0.29		
φm	Phase margin	R _L = 10 kΩ,	$C_L = 50 \text{ pF}$	25°C		37°		
		R _L = 10 kΩ,	$C_L = 0 pF$	230		42°		
	Gain margin	R _L = 10 kΩ,	C _L = 50 pF	25°C		3.1		dB
		R _L = 10 kΩ,	C _L = 0 pF	250		4		

[†] Full range is 0°C to 70°C for C suffix and -40°C to 125°C for I suffix. If not specified, full range is -40°C to 125°C.

[‡] Disable time and enable time are defined as the interval between application of the logic signal to SHDN and the point at which the supply current has reached half its final value.



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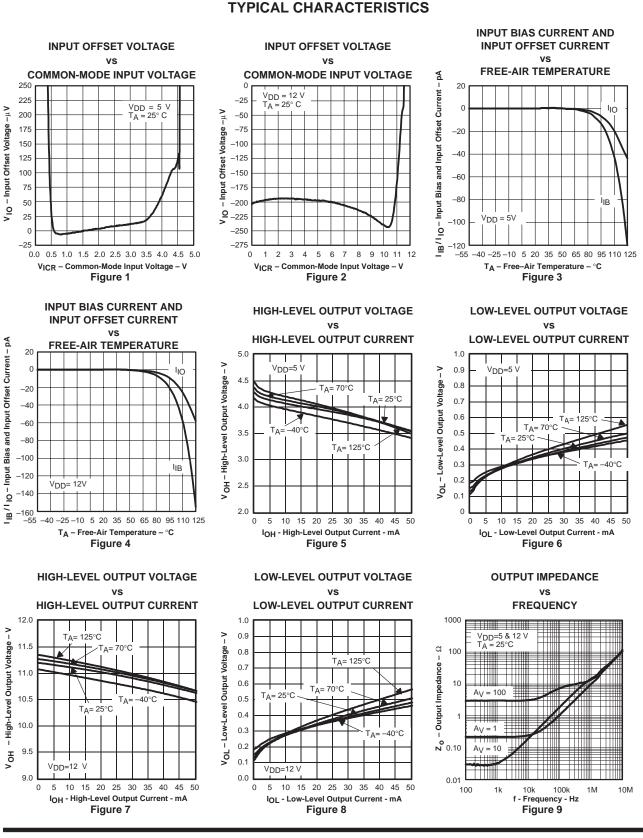
TYPICAL CHARACTERISTICS

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IDD	Supply current	vs Supply voltage	10
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CMRR	Common-mode rejection ratio	vs Frequency	12
Vn	Equivalent input noise voltage	vs Frequency	13
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	Shutdown forward isolation	vs Frequency	37, 38
	Shutdown reverse isolation	vs Frequency	39, 40
	Chutdown ownaky ownant	vs Supply voltage	41
	Shutdown supply current	vs Free-air temperature	42
	Shutdown pulse		43, 44

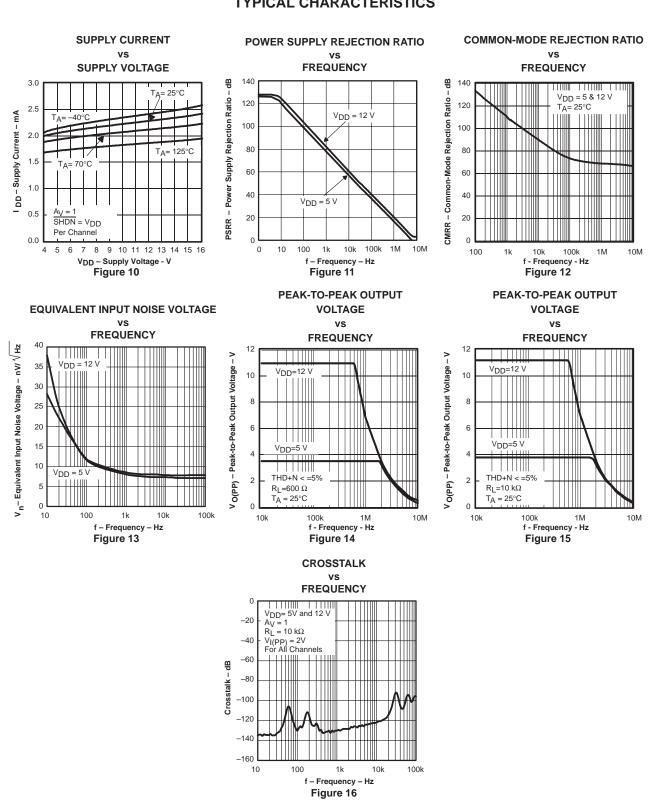


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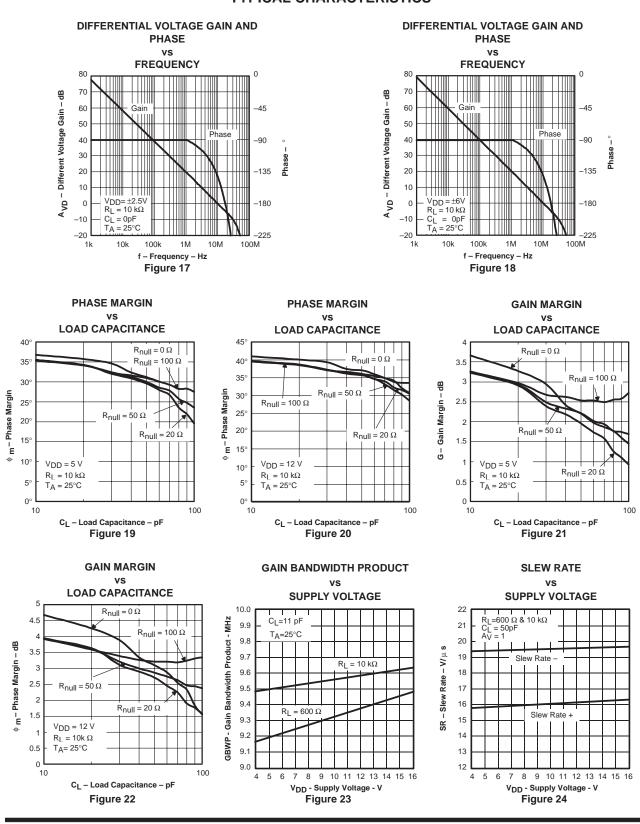
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TYPICAL CHARACTERISTICS



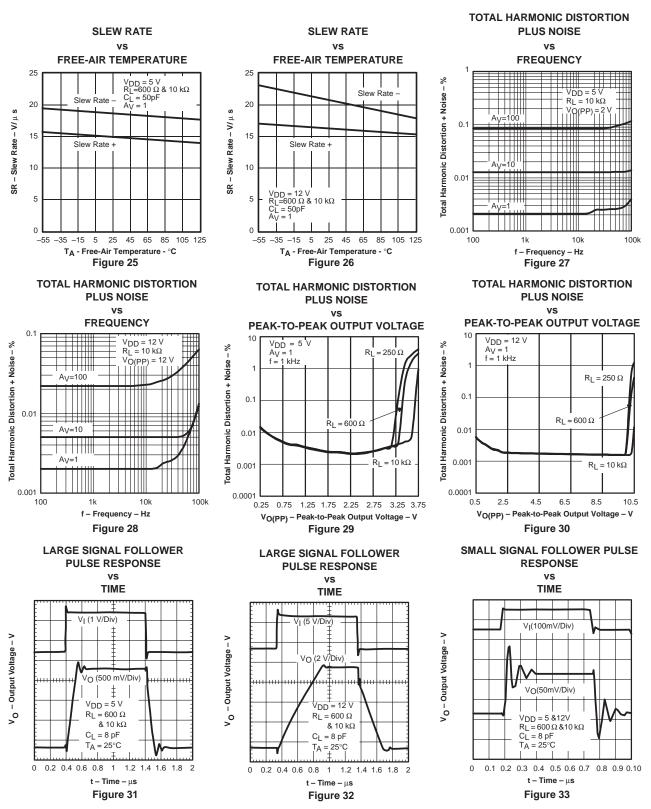
TLC070, TLC071, TLC072, TLC073, TLC074, TLC075, TLC07xA FAMILY OF WIDE-BANDWIDTH HIGH-OUTPUT-DRIVE SINGLE SUPPLY OPERATIONAL AMPLIFIERS SLOS219B – JUNE 1999 – REVISED NOVEMBER 1999



TYPICAL CHARACTERISTICS

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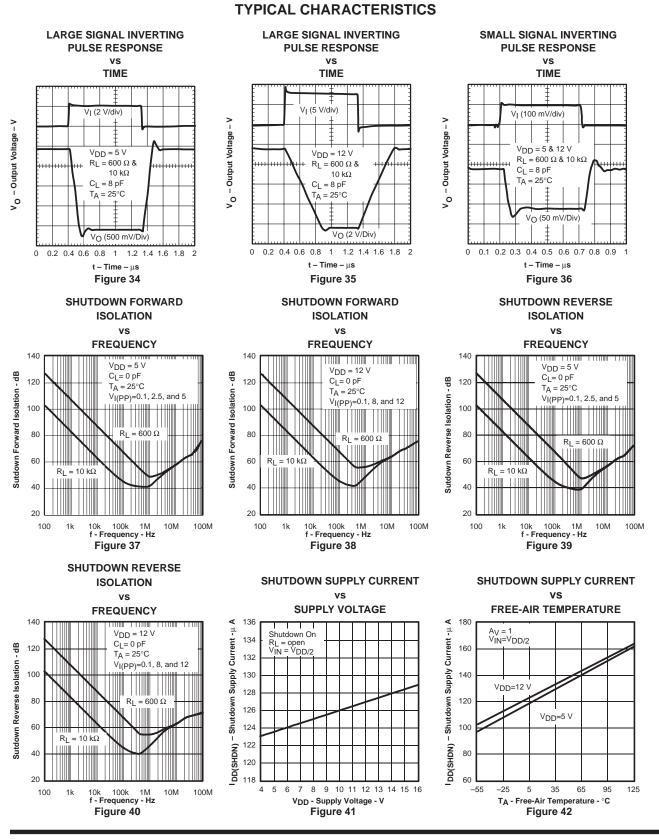
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TYPICAL CHARACTERISTICS



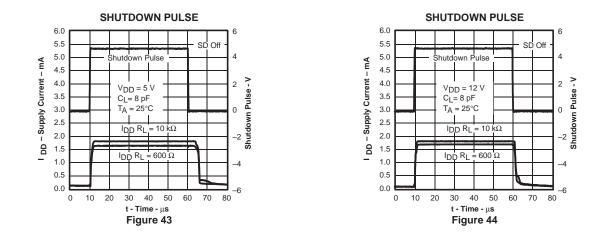
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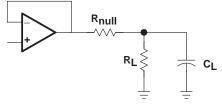


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TYPICAL CHARACTERISTICS



PARAMETER MEASUREMENT INFORMATION

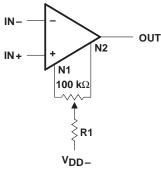


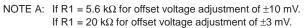


APPLICATION INFORMATION

input offset voltage null circuit

The TLC070 and TLC071 has an input offset nulling function. Refer to Figure 46 for the diagram.









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APPLICATION INFORMATION

driving a capacitive load

When the amplifier is configured in this manner, capacitive loading directly on the output will decrease the device's phase margin leading to high frequency ringing or oscillations. Therefore, for capacitive loads of greater than 10 pF, it is recommended that a resistor be placed in series (R_{NULL}) with the output of the amplifier, as shown in Figure 47. A minimum value of 20 Ω should work well for most applications.

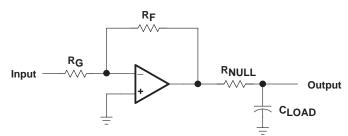


Figure 47. Driving a Capacitive Load

offset voltage

The output offset voltage, (V_{OO}) is the sum of the input offset voltage (V_{IO}) and both input bias currents (I_{IB}) times the corresponding gains. The following schematic and formula can be used to calculate the output offset voltage:

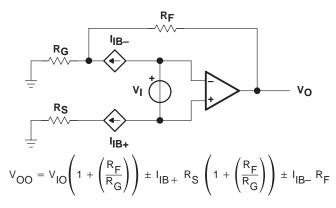


Figure 48. Output Offset Voltage Model



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APPLICATION INFORMATION

high speed CMOS input amplifiers

The TLC07x is a family of high-speed low-noise CMOS input operational amplifiers and has an input capacitance of the order of 20 pF. Any resistor used in the feedback path adds a pole in the transfer function equivalent to the input capacitance multiplied by the combination of source resistance and feedback resistance. For example, a gain of –10, source resistance of 1 k Ω and a feedback resistance of 10 k Ω adds an additional pole at approximately 8 MHz. This is more apparent with CMOS amplifiers than bipolar amplifiers due to their greater input capacitance.

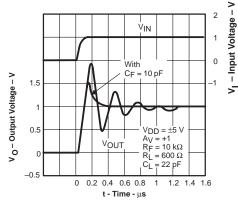
This is of little consequence on slower CMOS amplifiers, as this pole normally occurs at frequencies above their unity-gain bandwidth. However, the TLC07x with its 10-MHz bandwidth means that this pole normally occurs at frequencies where there is on the order of 5 dB gain left and the phase shift adds considerably.

The effect of this pole is the strongest with large feedback resistances at small closed loop gains. As the feedback resistance is increased, the gain peaking increases at a lower frequency and the 180° phase shift crossover point also moves down in frequency, decreasing the phase margin.

For the TLC07x, the maximum feedback resistor recommended is 5 k Ω , larger resistances can be used but a capacitor in parallel with the feedback resistor is recommended to counter the effects of the input capacitance pole.

The TLC073 with a 1-V step response has an 80% overshoot with a natural frequency of 3.5 MHz when configured as a unity gain buffer and with a $10-k\Omega$ feedback resistor. By adding a 10-pF capacitor in parallel with the feedback resistor, the overshoot is reduced to 40% and eliminates the natural frequency, resulting in a much faster settling time (see Figure 49). The 10-pF capacitor was chosen for convenience only.

Load capacitance had little effect on these measurements due to the excellent output drive capability of the TLC07x.



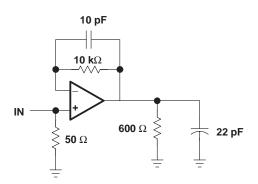


Figure 49. 1-V Step Response



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APPLICATION INFORMATION

general configurations

When receiving low-level signals, limiting the bandwidth of the incoming signals into the system is often required. The simplest way to accomplish this is to place an RC filter at the noninverting terminal of the amplifer (see Figure 50).

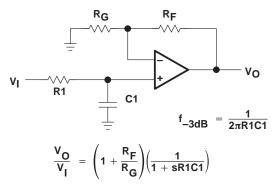


Figure 50. Single-Pole Low-Pass Filter

If even more attenuation is needed, a multiple pole filter is required. The Sallen-Key filter can be used for this task. For best results, the amplifier should have a bandwidth that is 8 to 10 times the filter frequency bandwidth. Failure to do this can result in phase shift of the amplifier.

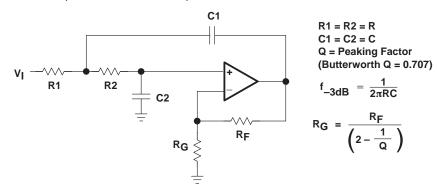


Figure 51. 2-Pole Low-Pass Sallen-Key Filter



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APPLICATION INFORMATION

shutdown function

Three members of the TLC07x family (TLC070/3/5) have a shutdown terminal (SHDN) for conserving battery life in portable applications. When the shutdown terminal is tied low, the supply current is reduced to 16 nA/channel, the amplifier is disabled, and the outputs are placed in a high-impedance mode. To enable the amplifier, the shutdown terminal can either be left floating or pulled high. When the shutdown terminal is left floating, care should be taken to ensure that parasitic leakage current at the shutdown terminal does not inadvertently place the operational amplifier into shutdown. The shutdown terminal threshold is always referenced to $V_{DD}/2$. Therefore, when operating the device with split supply voltages (e.g. ±2.5 V), the shutdown terminal needs to be pulled to $V_{DD}-$ (not GND) to disable the operational amplifier.

The amplifier's output with a shutdown pulse is shown in Figures 43 and 44. The amplifier is powered with a single 5-V supply and is configured as noninverting with a gain of 5. The amplifier turnon and turnoff times are measured from the 50% point of the shutdown pulse to the 50% point of the output waveform. The times for the single, dual, and quad are listed in the data tables.

Figures 37, 38, 39, and 40 show the amplifier's forward and reverse isolation in shutdown. The operational amplifier is configured as a voltage follower ($A_V = 1$). The isolation performance is plotted across frequency using 0.1 V_{PP}, 2.5 V_{PP}, and 5 V_{PP} input signals at ±2.5 V supplies and 0.1 V_{PP}, 8 V_{PP}, and 12 V_{PP} input signals at ±6 V supplies.

circuit layout considerations

To achieve the levels of high performance of the TLC07x, follow proper printed-circuit board design techniques. A general set of guidelines is given in the following.

- Ground planes It is highly recommended that a ground plane be used on the board to provide all
 components with a low inductive ground connection. However, in the areas of the amplifier inputs and
 output, the ground plane can be removed to minimize the stray capacitance.
- Proper power supply decoupling Use a 6.8-µF tantalum capacitor in parallel with a 0.1-µF ceramic capacitor on each supply terminal. It may be possible to share the tantalum among several amplifiers depending on the application, but a 0.1-µF ceramic capacitor should always be used on the supply terminal of every amplifier. In addition, the 0.1-µF capacitor should be placed as close as possible to the supply terminal. As this distance increases, the inductance in the connecting trace makes the capacitor less effective. The designer should strive for distances of less than 0.1 inches between the device power terminals and the ceramic capacitors.
- Sockets Sockets can be used but are not recommended. The additional lead inductance in the socket pins
 will often lead to stability problems. Surface-mount packages soldered directly to the printed-circuit board
 is the best implementation.
- Short trace runs/compact part placements Optimum high performance is achieved when stray series inductance has been minimized. To realize this, the circuit layout should be made as compact as possible, thereby minimizing the length of all trace runs. Particular attention should be paid to the inverting input of the amplifier. Its length should be kept as short as possible. This will help to minimize stray capacitance at the input of the amplifier.
- Surface-mount passive components Using surface-mount passive components is recommended for high
 performance amplifier circuits for several reasons. First, because of the extremely low lead inductance of
 surface-mount components, the problem with stray series inductance is greatly reduced. Second, the small
 size of surface-mount components naturally leads to a more compact layout thereby minimizing both stray
 inductance and capacitance. If leaded components are used, it is recommended that the lead lengths be
 kept as short as possible.



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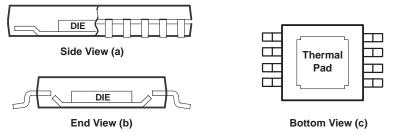
APPLICATION INFORMATION

general PowerPAD[™] design considerations

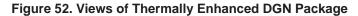
The TLC07x is available in a thermally-enhanced PowerPAD family of packages. These packages are constructed using a downset leadframe upon which the die is mounted [see Figure 52(a) and Figure 52(b)]. This arrangement results in the lead frame being exposed as a thermal pad on the underside of the package [see Figure 52(c)]. Because this thermal pad has direct thermal contact with the die, excellent thermal performance can be achieved by providing a good thermal path away from the thermal pad.

The PowerPAD package allows for both assembly and thermal management in one manufacturing operation. During the surface-mount solder operation (when the leads are being soldered), the thermal pad can also be soldered to a copper area underneath the package. Through the use of thermal paths within this copper area, heat can be conducted away from the package into either a ground plane or other heat dissipating device.

The PowerPAD package represents a breakthrough in combining the small area and ease of assembly of surface mount with the, heretofore, awkward mechanical methods of heatsinking.

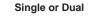


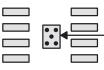
NOTE B: The thermal pad is electrically isolated from all terminals in the package.



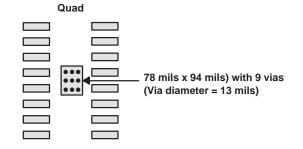
Although there are many ways to properly heatsink the PowerPAD package, the following steps illustrate the recommended approach.

Thermal Pad Area





_ 68 mils x 70 mils) with 5 vias (Via diameter = 13 mils





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APPLICATION INFORMATION

general PowerPAD design considerations (continued)

- 1. Prepare the PCB with a top side etch pattern as shown in Figure 53. There should be etch for the leads as well as etch for the thermal pad.
- 2. Place five holes (dual) or nine holes (quad) in the area of the thermal pad. These holes should be 13 mils in diameter. Keep them small so that solder wicking through the holes is not a problem during reflow.
- 3. Additional vias may be placed anywhere along the thermal plane outside of the thermal pad area. This helps dissipate the heat generated by the TLC07x IC. These additional vias may be larger than the 13-mil diameter vias directly under the thermal pad. They can be larger because they are not in the thermal pad area to be soldered so that wicking is not a problem.
- 4. Connect all holes to the internal ground plane.
- 5. When connecting these holes to the ground plane, **do not** use the typical web or spoke via connection methodology. Web connections have a high thermal resistance connection that is useful for slowing the heat transfer during soldering operations. This makes the soldering of vias that have plane connections easier. In this application, however, low thermal resistance is desired for the most efficient heat transfer. Therefore, the holes under the TLC07x PowerPAD package should make their connection to the internal ground plane with a complete connection around the entire circumference of the plated-through hole.
- 6. The top-side solder mask should leave the terminals of the package and the thermal pad area with its five holes (dual) or nine holes (quad) exposed. The bottom-side solder mask should cover the five or nine holes of the thermal pad area. This prevents solder from being pulled away from the thermal pad area during the reflow process.
- 7. Apply solder paste to the exposed thermal pad area and all of the IC terminals.
- 8. With these preparatory steps in place, the TLC07x IC is simply placed in position and run through the solder reflow operation as any standard surface-mount component. This results in a part that is properly installed.

For a given θ_{JA} , the maximum power dissipation is shown in Figure 54 and is calculated by the following formula:

$$\mathsf{P}_{\mathsf{D}} = \left(\frac{\mathsf{T}_{\mathsf{MAX}} - \mathsf{T}_{\mathsf{A}}}{\theta_{\mathsf{JA}}}\right)$$

Where:

P_D = Maximum power dissipation of TLC07x IC (watts)

- T_{MAX} = Absolute maximum junction temperature (150°C)
- T_A = Free-ambient air temperature (°C)

 $\theta_{JA} = \theta_{JC} + \theta_{CA}$

 θ_{JC} = Thermal coefficient from junction to case

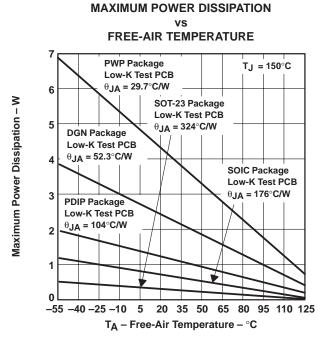
 θ_{CA} = Thermal coefficient from case to ambient air (°C/W)



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APPLICATION INFORMATION

general PowerPAD design considerations (continued)



NOTE A: Results are with no air flow and using JEDEC Standard Low-K test PCB.

The next consideration is the package constraints. The two sources of heat within an amplifier are quiescent power and output power. The designer should never forget about the quiescent heat generated within the device, especially muti-amplifier devices. Because these devices have linear output stages (Class A-B), most of the heat dissipation is at low output voltages with high output currents.

The other key factor when dealing with power dissipation is how the devices are mounted on the PCB. The PowerPAD devices are extremely useful for heat dissipation. But, the device should always be soldered to a copper plane to fully use the heat dissipation properties of the PowerPAD. The SOIC package, on the other hand, is highly dependent on how it is mounted on the PCB. As more trace and copper area is placed around the device, θ_{JA} decreases and the heat dissipation capability increases. The currents and voltages shown in these graphs are for the total package. For the dual or quad amplifier packages, the sum of the RMS output currents and voltages should be used to choose the proper package.



Figure 54. Maximum Power Dissipation vs Free-Air Temperature

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APPLICATION INFORMATION

macromodel information

Macromodel information provided was derived using Microsim *Parts*TM, the model generation software used with Microsim *PSpice*TM. The Boyle macromodel (see Note 1) and subcircuit in Figure 55 are generated using the TLC07x typical electrical and operating characteristics at $T_A = 25^{\circ}$ C. Using this information, output simulations of the following key parameters can be generated to a tolerance of 20% (in most cases):

- Maximum positive output voltage swing
- Maximum negative output voltage swing
- Slew rate
- Quiescent power dissipation
- Input bias current
- Open-loop voltage amplification

- Unity-gain frequency
- Common-mode rejection ratio
- Phase margin
- DC output resistance
- AC output resistance
- Short-circuit output current limit

PSpice and Parts are trademarks of MicroSim Corporation.



NOTE 1: G. R. Boyle, B. M. Cohn, D. O. Pederson, and J. E. Solomon, "Macromodeling of Integrated Circuit Operational Amplifiers," *IEEE Journal of Solid-State Circuits*, SC-9, 353 (1974).

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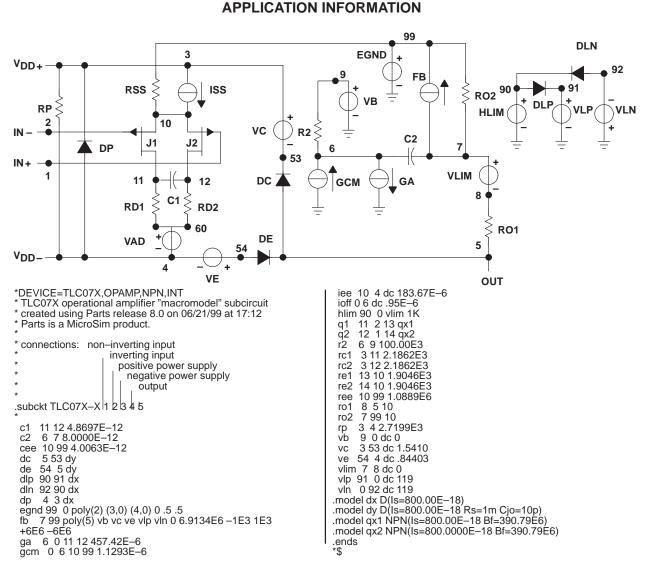


Figure 55. Boyle Macromodel and Subcircuit

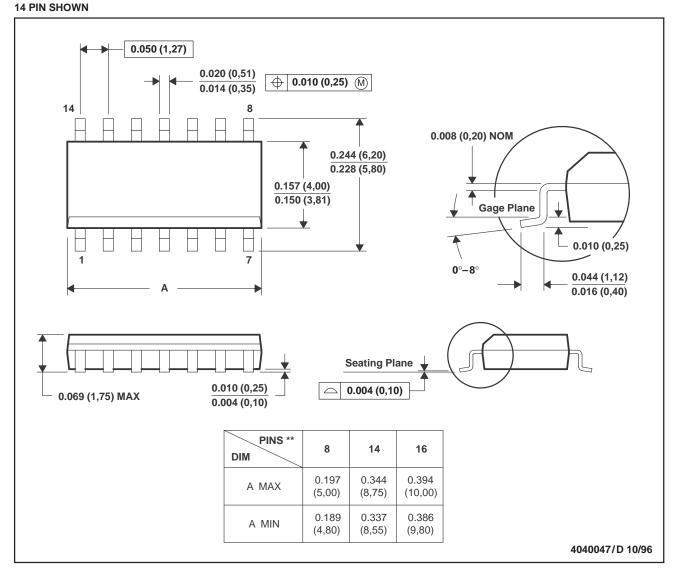


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MECHANICAL DATA

PLASTIC SMALL-OUTLINE PACKAGE

D (R-PDSO-G**)



NOTES: A. All linear dimensions are in inches (millimeters).

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion, not to exceed 0.006 (0,15).

D. Falls within JEDEC MS-012

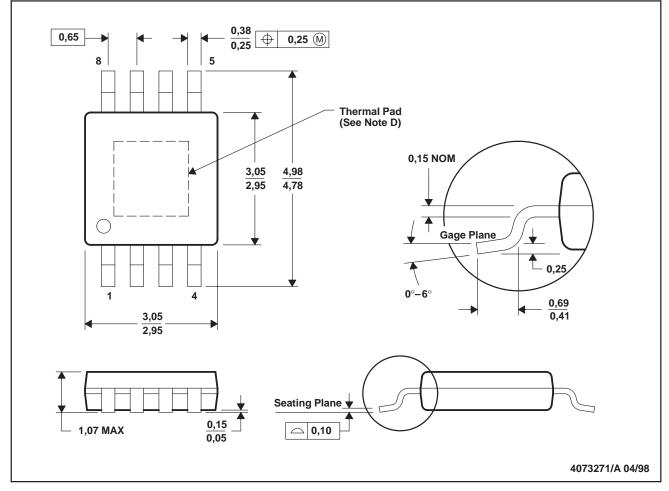


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MECHANICAL INFORMATION

DGN (S-PDSO-G8)

PowerPAD[™] PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Body dimensions include mold flash or protrusions.
- D. The package thermal performance may be enhanced by attaching an external heat sink to the thermal pad. This pad is electrically and thermally connected to the backside of the die and possibly selected leads. The dimension of the thermal pad is 68 mils (height as illustrated) × 70 mils (width as illustrated) (maximum). The pad is centered on the bottom of the package.

E. Falls within JEDEC MO-187

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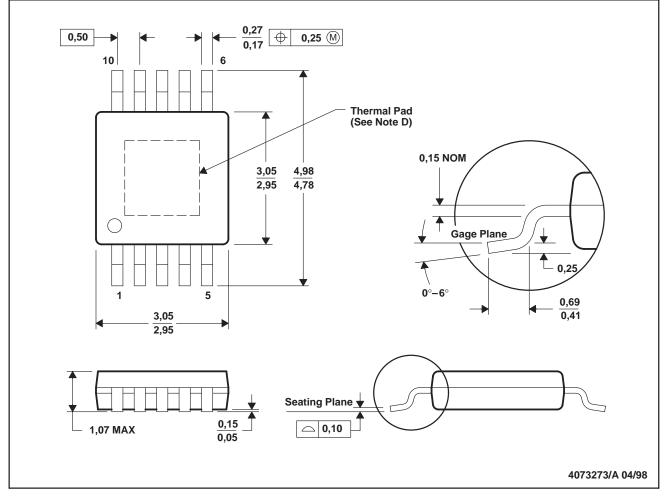


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MECHANICAL INFORMATION

DGQ (S-PDSO-G10)

PowerPAD™ PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion.

D. The package thermal performance may be enhanced by bonding the thermal pad to an external thermal plane.

This pad is electrically and thermally connected to the backside of the die and possibly selected leads. The dimension of the thermal pad is 68 mils (height as illustrated) \times 70 mils (width as illustrated) (maximum). The pad is centered on the bottom of the package.

PowerPAD is a trademark of Texas Instruments Incorporated.

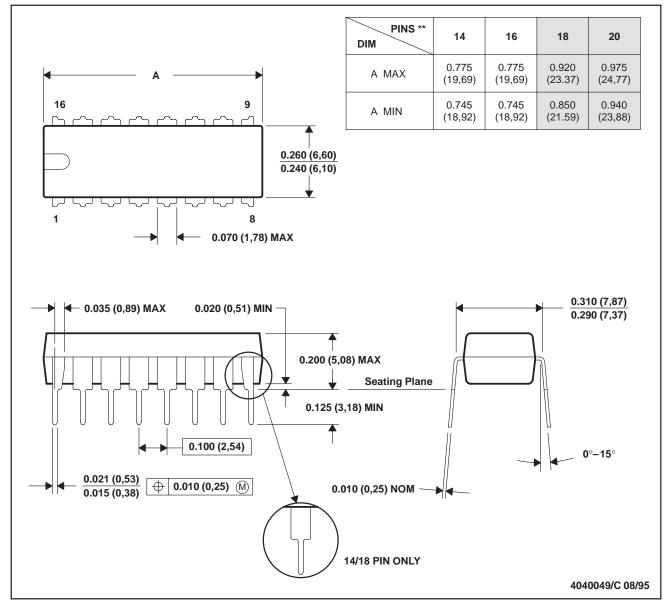


TLC070, TLC071, TLC072, TLC073, TLC074, TLC075, TLC07xA FAMILY OF WIDE-BANDWIDTH HIGH-OUTPUT-DRIVE SINGLE SUPPLY OPERATIONAL AMPLIFIERS SLOS219B – JUNE 1999 – REVISED NOVEMBER 1999

MECHANICAL INFORMATION

PLASTIC DUAL-IN-LINE PACKAGE

N (R-PDIP-T**) 16 PIN SHOWN



NOTES: A. All linear dimensions are in inches (millimeters).

B. This drawing is subject to change without notice.

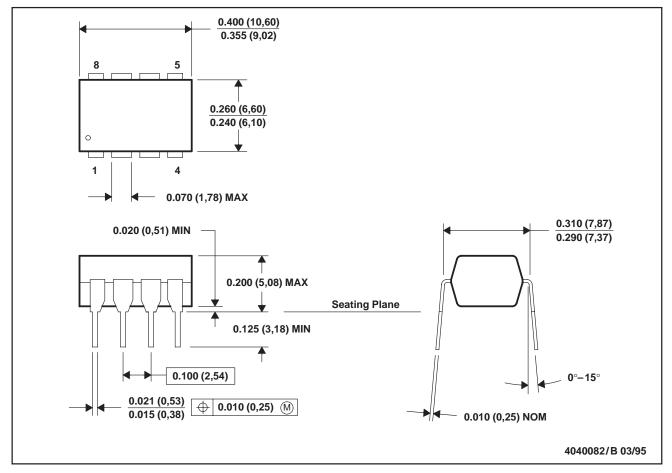
C. Falls within JEDEC MS-001 (20 pin package is shorter then MS-001.)



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MECHANICAL INFORMATION

PLASTIC DUAL-IN-LINE PACKAGE



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- C. Falls within JEDEC MS-001

P (R-PDIP-T8)



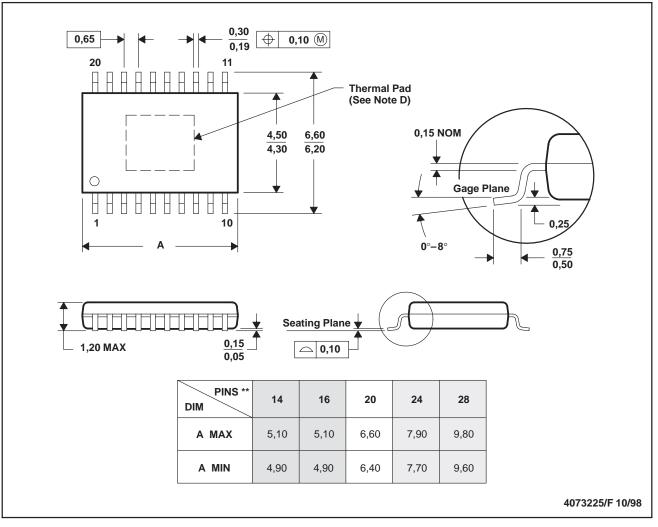
TLC070, TLC071, TLC072, TLC073, TLC074, TLC075, TLC07xA FAMILY OF WIDE-BANDWIDTH HIGH-OUTPUT-DRIVE SINGLE SUPPLY **OPERATIONAL AMPLIFIERS** SLOS219B - JUNE 1999 - REVISED NOVEMBER 1999

MECHANICAL INFORMATION

PWP (R-PDSO-G**)

20 PINS SHOWN

PowerPAD[™] PLASTIC SMALL-OUTLINE



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusions.

The package thermal performance may be enhanced by bonding the thermal pad to an external thermal plane. D.

This pad is electrically and thermally connected to the backside of the die and possibly selected leads. The dimension of the thermal pad is 78 mils (height as illustrated) × 94 mils (width as illustrated) (maximum). The pad is centered on the bottom of the package. E. Falls within JEDEC MO-153



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